

R-C Thermal Model Parameters

DESCRIPTION

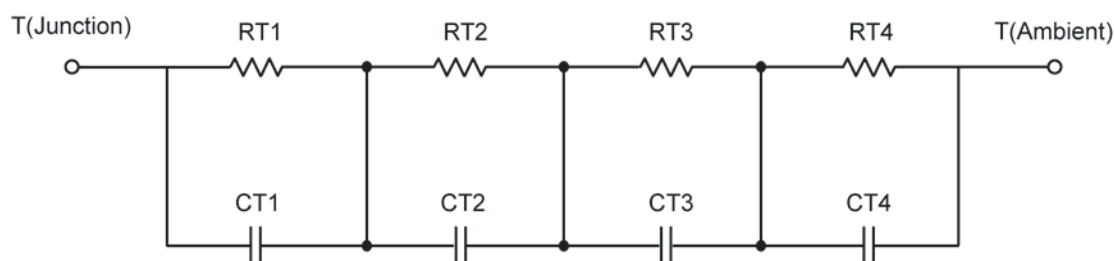
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

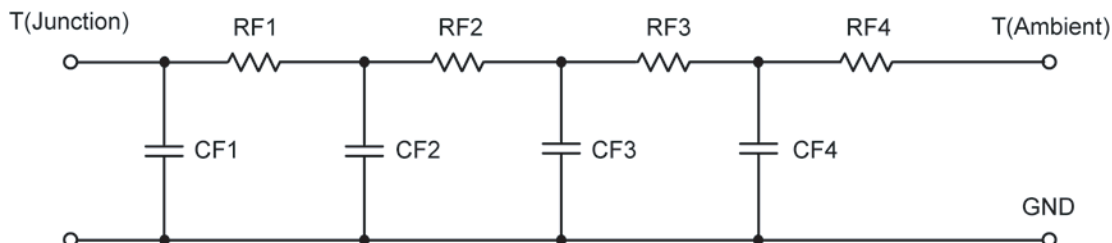
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|--|------------|------|------------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 6.4416 | N/A | 18.8138 |
| RT2 | 18.6004 | N/A | 3.6041 |
| RT3 | 35.8250 | N/A | 4.1935 |
| RT4 | 59.1597 | N/A | 18.4883 |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 716.9061 u | N/A | 3.4647 m |
| CT2 | 10.3032 m | N/A | 184.3513 u |
| CT3 | 45.9017 m | N/A | 734.8021 m |
| CT4 | 1.3185 | N/A | 41.5016 m |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance ($^{\circ}\text{C}/\text{W}$) | | | |
|--|------------|------|------------|
| Junction to | Ambient | Case | Foot |
| RF1 | 7.6669 | N/A | 5.9532 |
| RF2 | 28.9384 | N/A | 20.2620 |
| RF3 | 27.8091 | N/A | 7.5854 |
| RF4 | 55.5893 | N/A | 11.2831 |
| Thermal Capacitance (Joules/ $^{\circ}\text{C}$) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 746.8655 u | N/A | 303.2746 u |
| CF2 | 8.1962 m | N/A | 4.0194 m |
| CF3 | 59.4462 m | N/A | 24.7919 m |
| CF4 | 1.3572 | N/A | 70.7509 m |

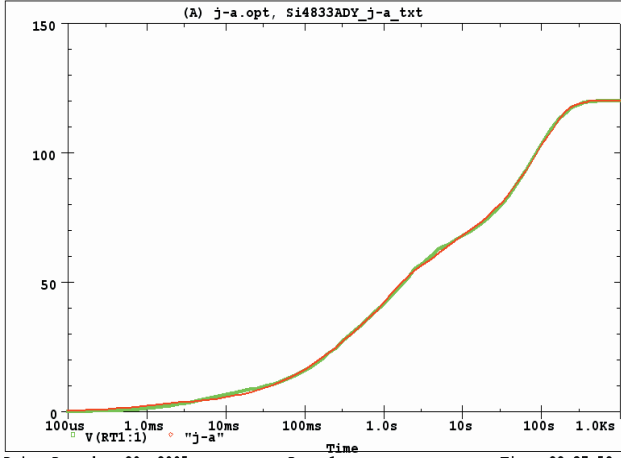
Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

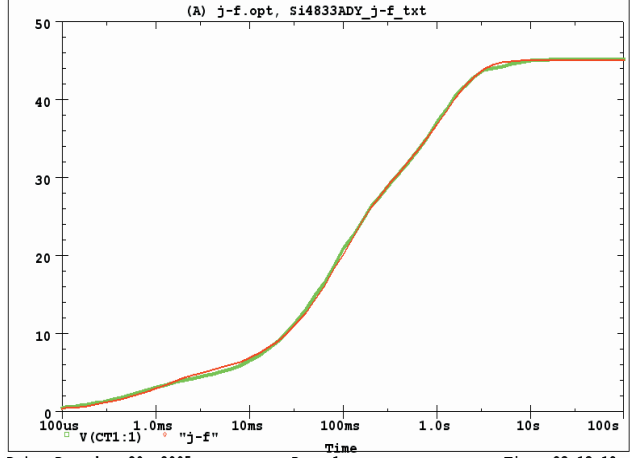


Si4833ADY Tank j-a Temperature: 27.0



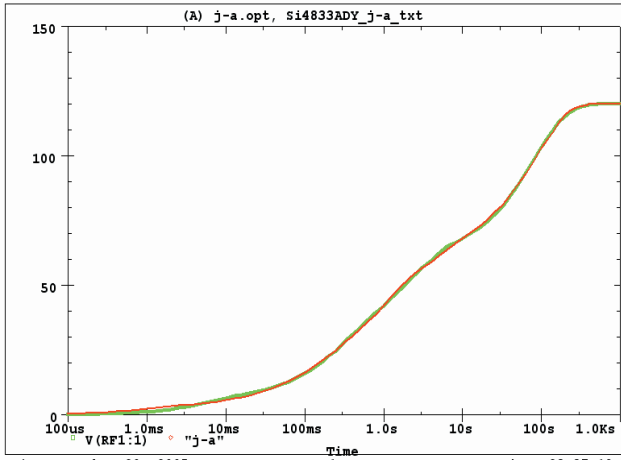
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Si4833ADY Tank j-f Temperature: 27.0



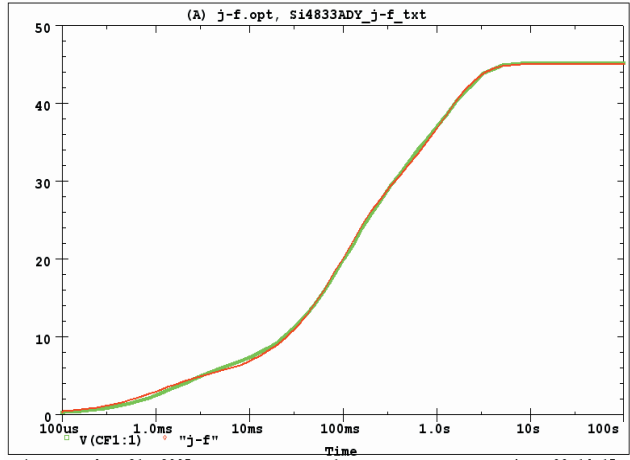
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Si4833ADY Filter j-a Temperature: 27.0



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